TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

2SD2481

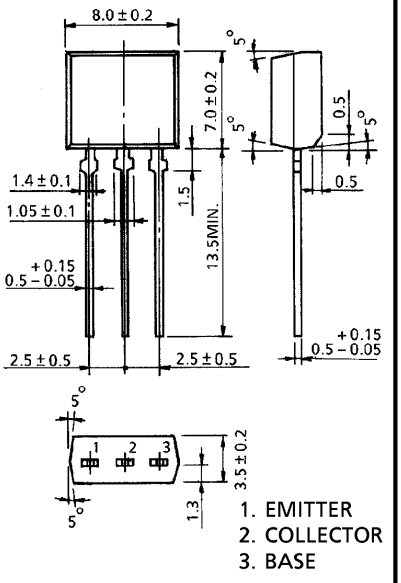
PULSE MOTOR DRIVE, HAMMER DRIVE APPLICATIONS

SWITCHING APPLICATIONS

POWER AMPLIFIER APPLICATIONS

- High DC Current Gain : h_{FE} = 4000 (Min.)
- Low Saturation Voltage : $V_{CE\ (sat)}$ = 1.5V (Max.)

Unit in mm



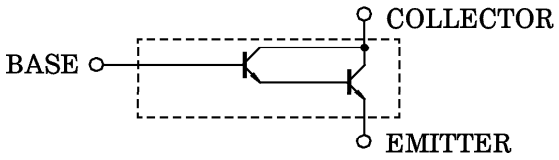
JEDEC	—
EIAJ	—
TOSHIBA	2-8M1A

Weight : 0.55g (Typ.)

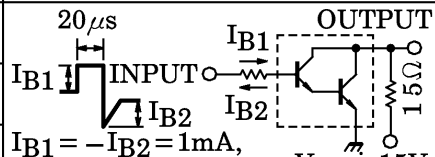
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Base Voltage	V_{EBO}	10	V
Collector Current	I_C	1.5	A
Base Current	I_B	0.15	A
Collector Power Dissipation	P_C	1.3	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	−55~150	°C

EQUIVALENT CIRCUIT

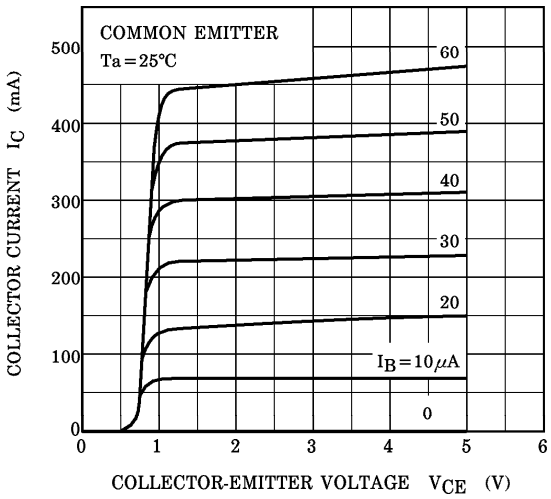


ELECTRICAL CHARACTERISTICS (Ta = 25°C)

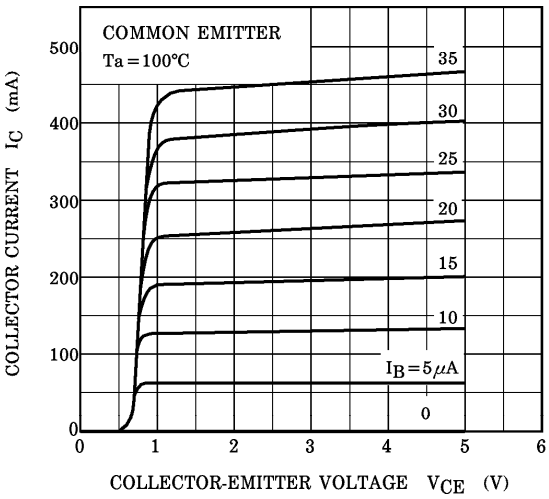
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I_{CBO}	V_{CB} = 30V, I_E = 0	—	—	10	μA
Emitter Cut-off Current		I_{EBO}	V_{EB} = 10V, I_C = 0	—	—	10	μA
Collector-Emitter Breakdown Voltage		$V_{(BR)\ CEO}$	I_C = 10mA, I_B = 0	30	—	—	V
DC Current Gain		h_{FE}	V_{CE} = 2V, I_C = 150mA	4000	—	—	
Saturation Voltage	Collector-Emitter	$V_{CE\ (sat)}$	I_C = 1A, I_B = 1mA	—	—	1.5	V
	Base-Emitter	$V_{BE\ (sat)}$	I_C = 1A, I_B = 1mA	—	—	2.2	
Switching Time	Turn-On Time	t_{on}		—	0.18	—	μs
	Storage Time	t_{stg}		—	0.6	—	
	Fall Time	t_f		—	0.3	—	

$I_{B1} = -I_{B2}$ = 1mA, DUTY CYCLE ≦ 1%

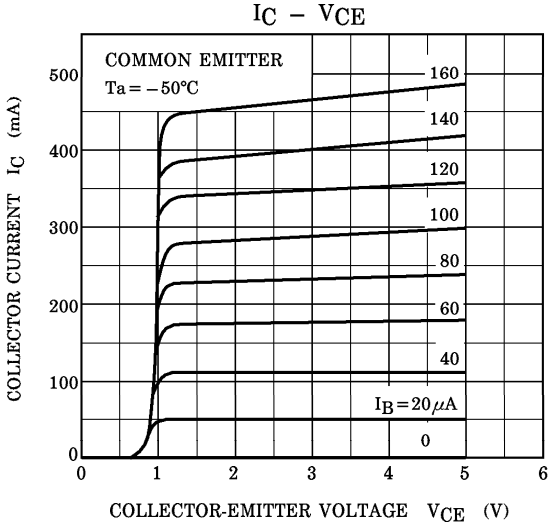
$I_C - V_{CE}$



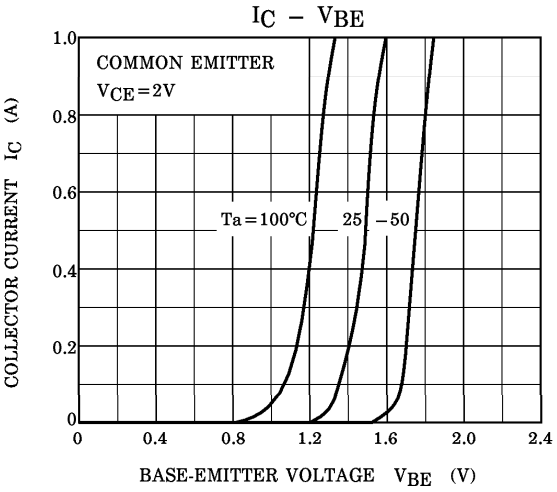
$I_C - V_{CE}$



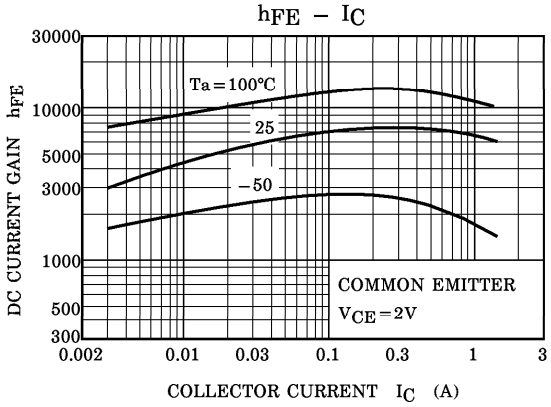
$I_C - V_{CE}$



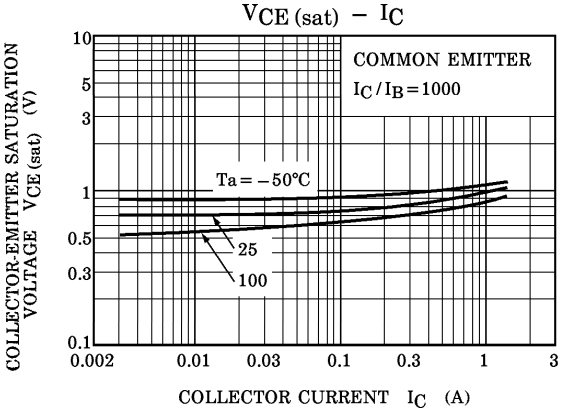
$I_C - V_{BE}$



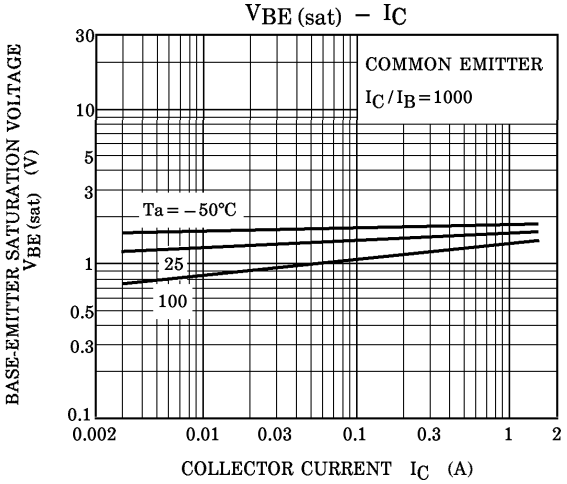
$h_{FE} - I_C$



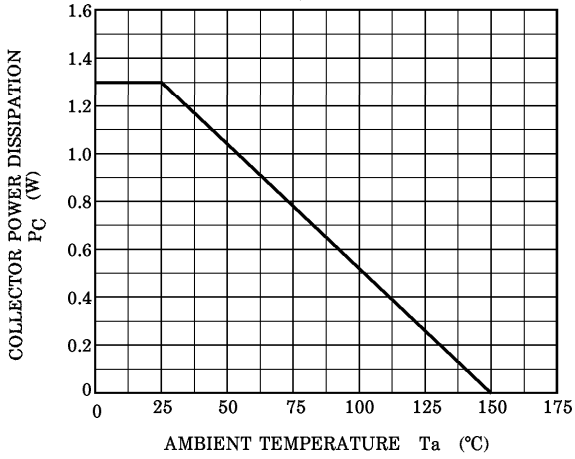
$V_{CE\,(sat)} - I_C$



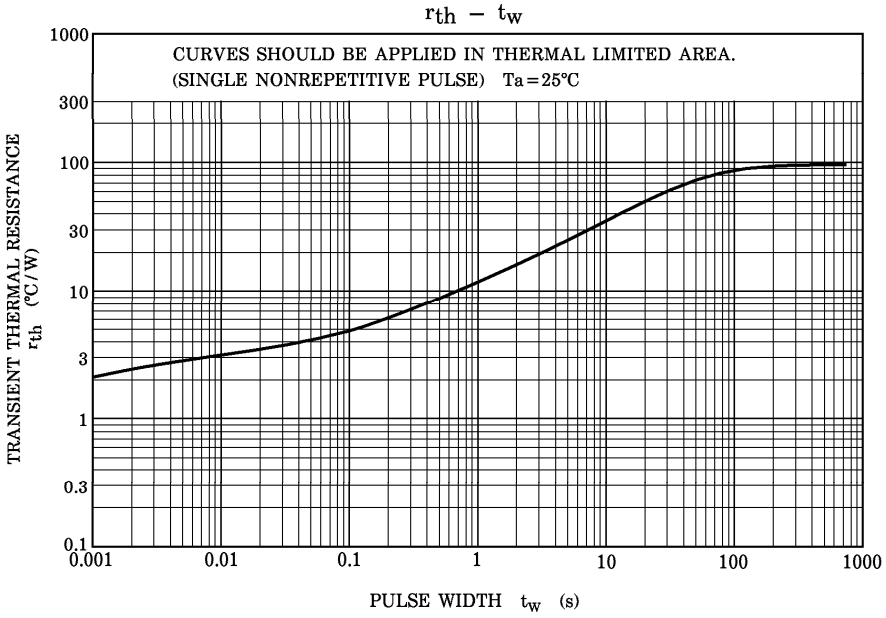
$V_{BE\,(sat)}$ – I_C



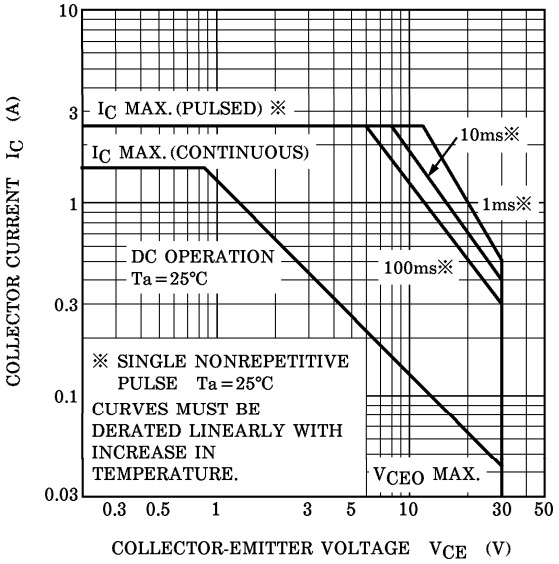
P_C – Ta



r_{th} – t_w



SAFE OPERATING AREA



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